

# Radar Pulsed Power Transistor, 4W, 100μs Pulse, 10% Duty 1.2 - 1.4 GHz PH1214-4M

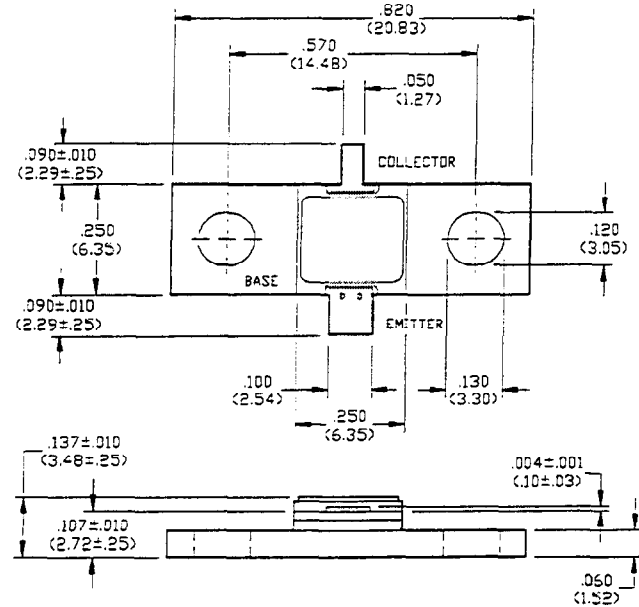
V2.00

## Features

- NPN Silicon Microwave Power Transistor
- Common Base Configuration
- Broadband Class C Operation
- Interdigitated Geometry
- Diffused Emitter Ballasting Resistors
- Gold Metalization System
- Internal Input Impedance Matching
- Hermetic Metal/Ceramic Package

## Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CES}$	65	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	$I_C$	875	mA
Total Power Dissipation	$P_{TOT}$	17	W
Junction Temperature	$T_J$	200	°C
Storage Temperature	$T_{STG}$	-65 to +200	°C



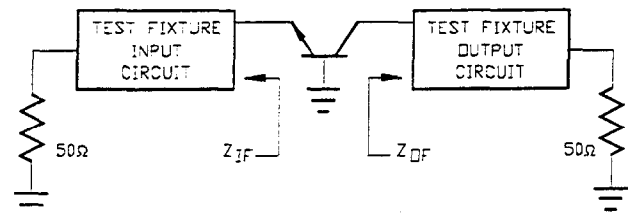
UNLESS OTHERWISE NOTED, TOLERANCES ARE INCHES = .005" (MILLIMETERS = ±.13MM)

## Electrical Characteristics at 25°C

Parameter	Symbol	Min	Max	Units	Test Conditions
Collector-Emitter Breakdown Voltage	$BV_{CES}$	65	-	V	$I_C = 8 \text{ mA}$
Collector-Emitter Leakage Current	$I_{CES}$	-	1.0	mA	$V_{CE} = 40 \text{ V}$
Thermal Resistance	$R_{TH(JC)}$	-	8.6	°C/W	$V_{CC} = 28 \text{ V}$ , $P_{IN} = 800 \text{ mW}$ , $F = 1.20, 1.30, 1.40 \text{ GHz}$
Output Power	$P_{OUT}$	4.0	-	W	$V_{CC} = 28 \text{ V}$ , $P_{IN} = 800 \text{ mW}$ , $F = 1.20, 1.30, 1.40 \text{ GHz}$
Power Gain	$G_P$	7.0	-	dB	$V_{CC} = 28 \text{ V}$ , $P_{IN} = 800 \text{ mW}$ , $F = 1.20, 1.30, 1.40 \text{ GHz}$
Collector Efficiency	$\eta_C$	45	-	%	$V_{CC} = 28 \text{ V}$ , $P_{IN} = 800 \text{ mW}$ , $F = 1.20, 1.30, 1.40 \text{ GHz}$
Input Return Loss	RL	6	-	dB	$V_{CC} = 28 \text{ V}$ , $P_{IN} = 800 \text{ mW}$ , $F = 1.20, 1.30, 1.40 \text{ GHz}$
Load Mismatch Tolerance	VSWR-T	-	3:1	-	$V_{CC} = 28 \text{ V}$ , $P_{IN} = 800 \text{ mW}$ , $F = 1.20, 1.30, 1.40 \text{ GHz}$
Load Mismatch Stability	VSWR-S	-	1.5:1	-	$V_{CC} = 28 \text{ V}$ , $P_{IN} = 800 \text{ mW}$ , $F = 1.20, 1.30, 1.40 \text{ GHz}$

## Broadband Test Fixture Impedances

F(GHz)	$Z_{IF}(\Omega)$	$Z_{OF}(\Omega)$
1.20	$7.0 - j4.5$	$12.0 + j24$
1.30	$6.4 - j3.0$	$12.5 + j21$
1.40	$6.0 - j1.5$	$10.5 + j24$



Specifications Subject to Change Without Notice.

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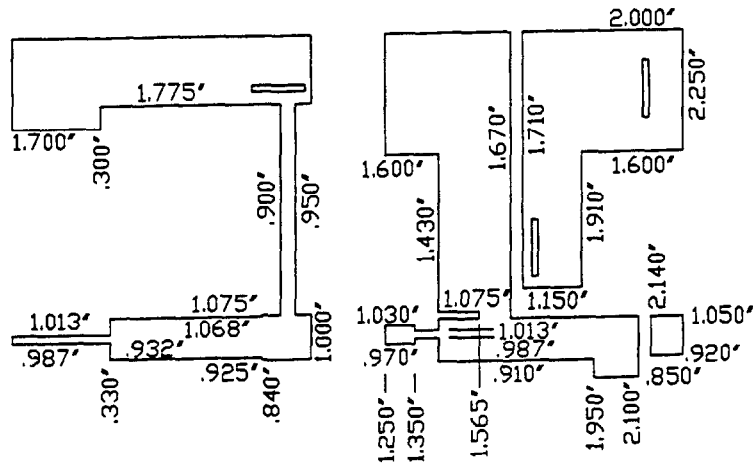
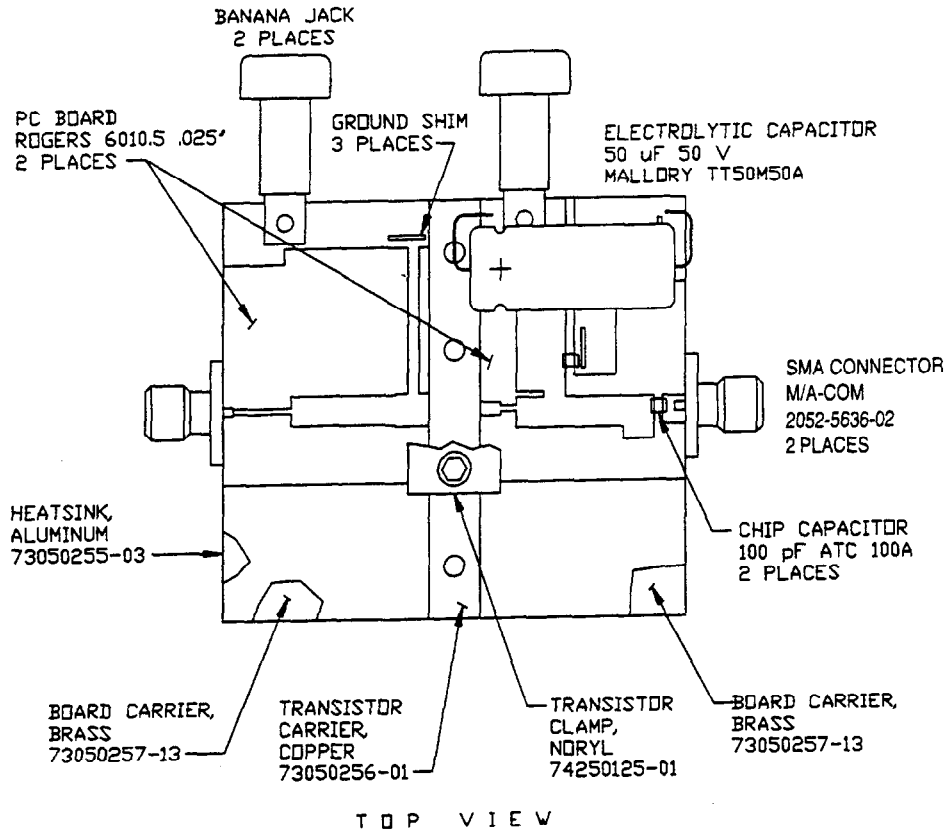
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RF Test Fixture



CIRCUIT DIMENSIONS

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